



Micro Commercial Components

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MMDT5401

Features

- Marking:K4M
- Ideal for Low Power Amplification and Switching
- Ultra-small Surface Mount Package
- Epitaxial Planar Die Construction
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0 and MSL Rating 1

Maximum Ratings @ 25°C Unless Otherwise Specified

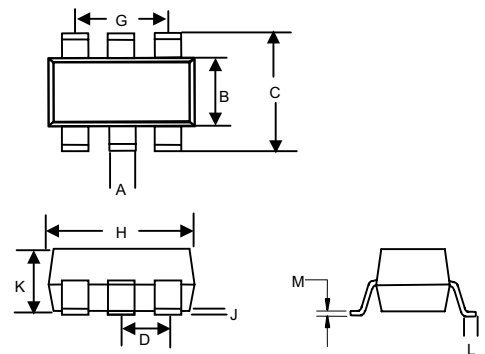
Symbol	Rating	Rating	Unit
V_{CEO}	Collector-Emitter Voltage	-150	V
V_{CBO}	Collector-Base Voltage	-160	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current-Continuous	-0.2	A
P_C	Collector Dissipation	0.2	W
T_J	Operating Junction Temperature	-55 to +150	°C
T_{STG}	Storage Temperature	-55 to +150	°C

Electrical Characteristics @ 25°C Unless Otherwise Specified

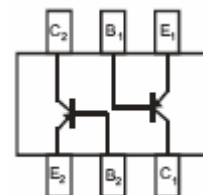
Symbol	Parameter	Min	Max	Units
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ($I_C=-1mA$, $I_B=0$)	-150	---	Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=-100\mu A$, $I_E=0$)	-160	---	Vdc
$V_{(BR)EBO}$	Collector-Emitter Breakdown Voltage ($I_E=-10\mu A$, $I_C=0$)	-5	---	Vdc
I_{CBO}	Collector Cutoff Current ($V_{CB}=-120V$, $I_E=0$)	---	0.05	μA
I_{EBO}	Emitter Cutoff Current ($V_{EB}=-3V$, $I_C=0$)	---	-0.05	μA
h_{FE}	DC Current Gain ($I_C=-1mA$, $V_{CE}=-5V$) ($I_C=-10mA$, $V_{CE}=-5V$) ($I_C=-50mA$, $V_{CE}=-5V$)	50 60 50	--- 240 ---	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=-10mA$, $I_B=-1mA$) ($I_C=-50mA$, $I_B=-5mA$)	---	-0.2 -0.5	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C=-10mA$, $I_B=-1mA$) ($I_C=-50mA$, $I_B=-5mA$)	---	-1 -1	Vdc
f_T	Current Gain-Bandwidth Product ($V_{CE}=-10V$, $I_C=-10mA$, $f=100MHz$)	100	300	MHz
C_{ob}	Output Capacitance ($V_{CB}=-5V$, $f=1.0MHz$, $I_E=0$)	---	4.5	pF
NF	Noise Figure ($V_{CE}=-10V$, $I_C=-0.1mA$, $f=1KHz$, $R_S=1k\Omega$)	---	6	dB
t_d	Delay Time $V_{CC}=-3V$, $I_C=-10mA$, $V_{BE}=-0.5V$, $I_{B1}=-I_{B2}=-1mA$	---	35	ns
t_r	Rise Time	---	35	ns
t_s	Storage Time $V_{CC}=-3V$, $I_C=-10mA$, $I_{B1}=-I_{B2}=-1mA$	---	225	ns
t_f	Fall Time	---	75	ns

Plastic-Encapsulate Transistors

SOT-363



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.006	.014	0.15	0.35	
B	.045	.053	1.15	1.35	
C	.085	.096	2.15	2.45	
D	.026		0.65Nominal		
G	.047	.055	1.20	1.40	
H	.071	.087	1.80	2.20	
J	---	.004	---	0.10	
K	.035	.043	0.90	1.10	
L	.010	.018	0.26	0.46	
M	.003	.006	0.08	0.15	



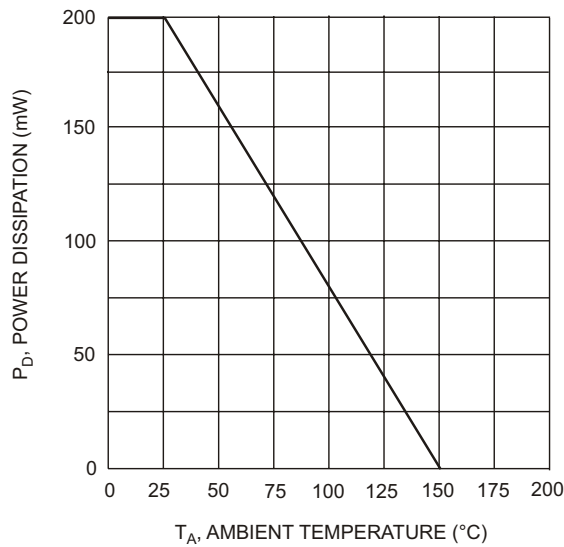


Fig. 1, Max Power Dissipation vs Ambient Temperature

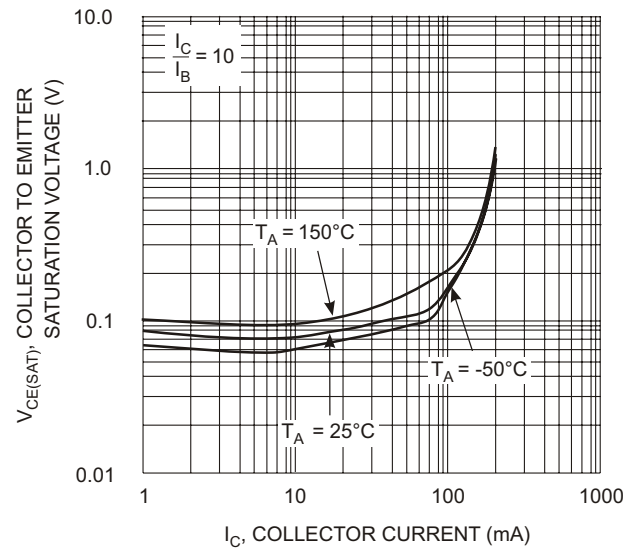


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

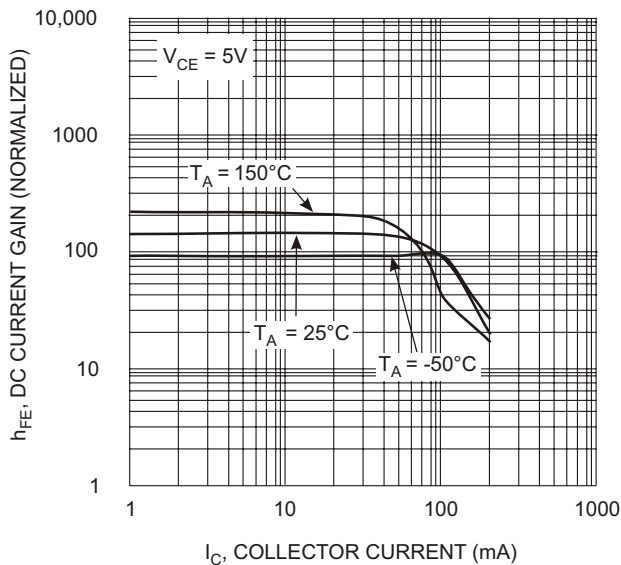


Fig. 3, DC Current Gain vs. Collector Current

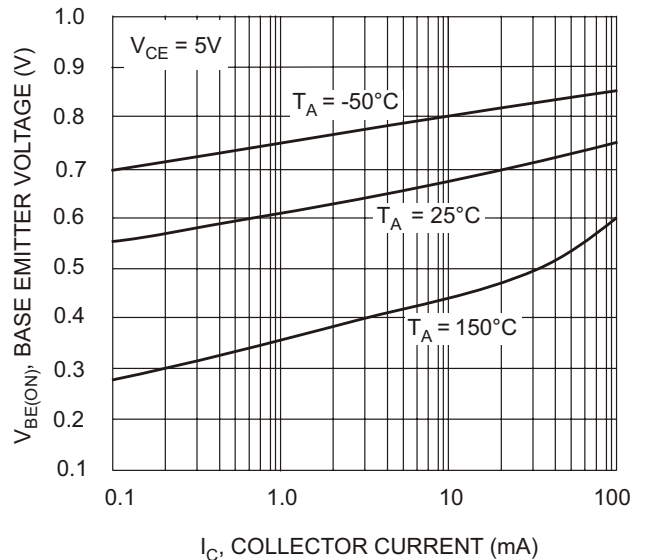


Fig. 4, Base Emitter Voltage vs. Collector Current

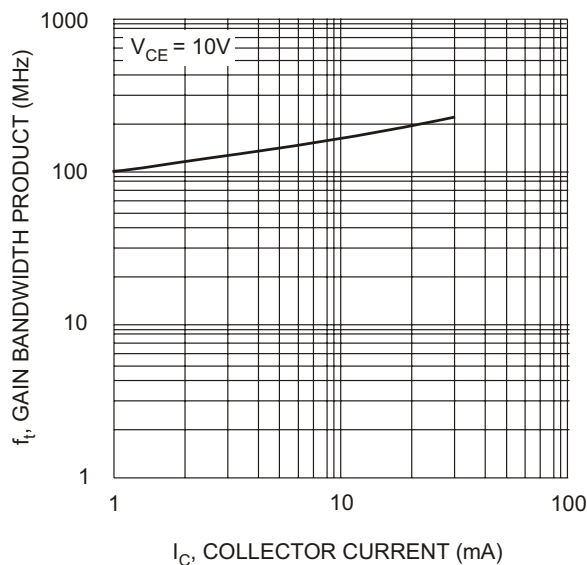


Fig. 5, Gain Bandwidth Product vs Collector Current

Ordering Information

Device	Packing
(Part Number)-TP	Tape&Reel;3Kpcs/Reel

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